

# Automotive High Performance Logic Gates

## NLV18SZxx, NLV28WZxx

The NLV18SZxx are automotive-grade High Performance single CMOS logic gates. The NLV28WZxx are automotive-grade high Performance Dual CMOS logic gates.

### Features

- High Speed:  $t_{PD} = 3.7 \text{ ns (Typ)}$  at  $V_{CC} = 3.0 \text{ V}$
- Low Power Dissipation:  $I_{CC} = 1 \mu\text{A (Max)}$  at  $T_A = 25^\circ\text{C}$
- High Noise Immunity
- Balanced Propagation Delays ( $t_{PLH} = t_{PHL}$ )
- Symmetrical Output Impedance ( $I_{OH} = I_{OL} = 24 \text{ mA @ } V_{CC} = 3.0 \text{ V}$ )
- Operating Temperature:  $-55^\circ\text{C}$  to  $+125^\circ\text{C}$   
AEC Grade 1-Compliant:  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$
- Tiny SC-88A and SC-88 Packages (other package offerings may be available upon request)
- AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and RoHS Compliant

### FUNCTION LIST

xx	Function
00	2-Input NAND
02	2-Input NOR
04	Inverter
06	Open-Drain Inverter
07	Open-Drain Buffer
08	2-Input AND
14	Schmitt-Trigger Inverter
17	Schmitt-Trigger Buffer
32	2-Input OR
16	Buffer
86	2-Input XOR
125	Tri-State Buffer
126	Tri-State Buffer
U04	Unbuffered Inverter



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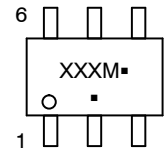
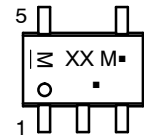


SC-88A  
DF SUFFIX  
CASE 419A



SC-88  
CASE 419B

### MARKING DIAGRAM



XX = Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

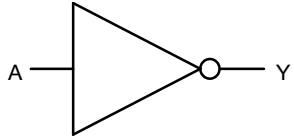
\*Date Code orientation and/or position may vary depending upon manufacturing location.

### ORDERING INFORMATION

See detailed ordering and shipping information on page 9 of this data sheet.

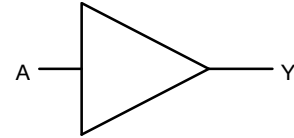
# NLV18SZxx, NLV28WZxx

## Functions and Function Tables – Buffers and Inverters



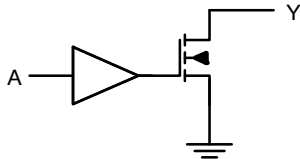
**04 - Inverter**  
**U04 - Unbuffered Inverter**

A	Y
0	1
1	0



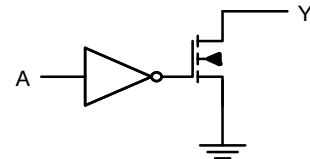
**16 - Buffer**

A	Y
0	0
1	1



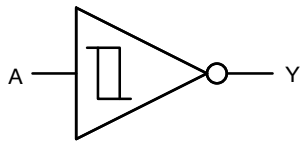
**06 - Open-Drain Inverter**

A	Y
0	Hi-Z
1	0



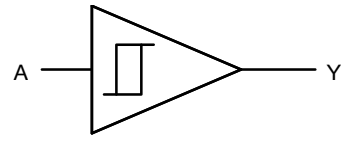
**07 - Open-Drain Buffer**

A	Y
0	0
1	Hi-Z



**14 - Schmitt-Trigger Inverter**

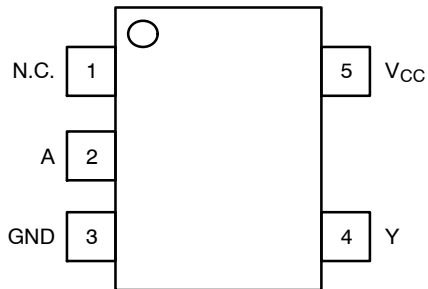
A	Y
0	1
1	0



**17 - Schmitt-Trigger Buffer**

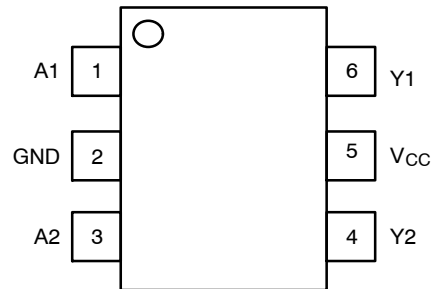
A	Y
0	0
1	1

### Pin Assignment



**Pinout (Buffers and Inverters)**

Pin	Name	Description
1	N.C.	No Connection
2	A	Input
3	GND	Ground
4	Y	Output
5	V <sub>CC</sub>	Supply

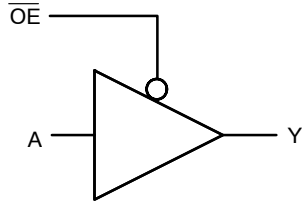


**Pinout (Buffers and Inverters)**

Pin	Name	Description
1	A1	Input 1
2	GND	Ground
3	A2	Input 2
4	Y	Output 2
5	V <sub>CC</sub>	Supply
6	Y1	Output 1

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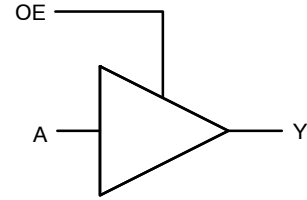
## Functions and Function Tables – Tri-State Buffers and Bus Drivers



125 - Tri-State Buffer

OE	A	Y
0	0	0
0	1	1
1	X	Hi-Z

X = Don't Care

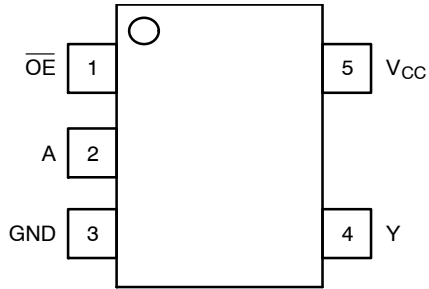


126 - Tri-State Buffer

OE	A	Y
0	X	Hi-Z
1	0	0
1	1	1

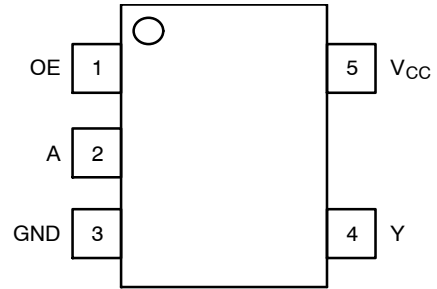
X = Don't Care

### Pin Assignments



Pinout (125)

Pin	Name	Description
1	OE	Enable (Active-Low)
2	A	Input
3	GND	Ground
4	Y	Output
5	V <sub>CC</sub>	Supply

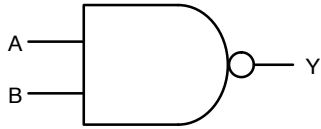


Pinout (126)

Pin	Name	Description
1	OE	Enable (Active-High)
2	A	Input
3	GND	Ground
4	Y	Output
5	V <sub>CC</sub>	Supply

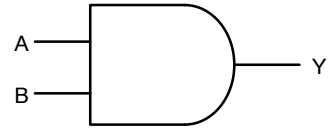
# NLV18SZxx, NLV28WZxx

## Functions and Function Tables – Gates



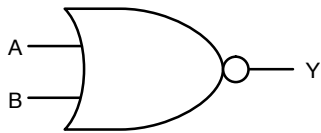
00 - NAND

A	B	Y
0	0	1
0	1	1
1	0	1
1	1	0



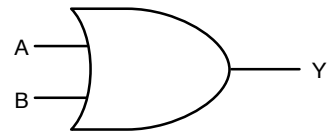
08 - AND

A	B	Y
0	0	0
0	1	0
1	0	0
1	1	1



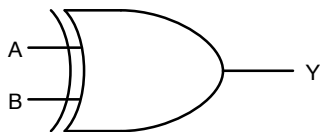
02 - NOR

A	B	Y
0	0	1
0	1	0
1	0	0
1	1	0



32 - OR

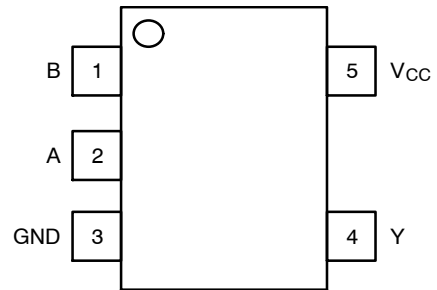
A	B	Y
0	0	0
0	1	1
1	0	1
1	1	1



86 - XOR

A	B	Y
0	0	0
0	1	1
1	0	1
1	1	0

### Pin Assignment



Pinout (Gates)

Pin	Name	Description
1	B	Input
2	A	Input
3	GND	Ground
4	Y	Output
5	V <sub>CC</sub>	Supply

# NLV18SZxx, NLV28WZxx

**Table 1. MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit	
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +6.5	V	
V <sub>IN</sub>	DC Input Voltage	-0.5 to +6.5	V	
V <sub>OUT</sub>	DC Output Voltage (U04)	-0.5 to V <sub>CC</sub> +0.5	V	
	DC Output Voltage (Other functions)	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)		-0.5 to V <sub>CC</sub> +0.5 -0.5 to +6.5 -0.5 to +6.5
I <sub>IK</sub>	DC Input Diode Current	-50	mA	
I <sub>OK</sub>	DC Output Diode Current	-50	mA	
I <sub>OUT</sub>	DC Output Source/Sink Current	±50	mA	
I <sub>CC</sub> or I <sub>GND</sub>	DC Supply Current Per Supply Pin or Ground Pin	±100	mA	
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C	
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C	
T <sub>J</sub>	Junction Temperature Under Bias	+150	°C	
θ <sub>JA</sub>	Thermal Resistance (Note 2)	659	°C/W	
P <sub>D</sub>	Power Dissipation in Still Air at 85°C	190	mW	
MSL	Moisture Sensitivity	Level 1		
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34 UL 94 V-0 @ 0.125 in		
V <sub>ESD</sub>	ESD Withstand Voltage (Note 3)	Human Body Model	2000	V
		Charged Device Model	1000	
I <sub>LATCHUP</sub>	Latchup Performance (Note 4)	±100	mA	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri-stated.
2. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 20 ounce copper trace with no air flow.
3. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.
4. Tested to EIA/JESD78 Class II.

**Table 2. RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit	
V <sub>CC</sub>	Positive DC Supply Voltage	1.65	5.5	V	
V <sub>IN</sub>	Digital Input Voltage	0	5.5	V	
V <sub>OUT</sub>	DC Output Voltage (U04)	0	V <sub>CC</sub>	V	
	DC Output Voltage (Other functions)	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	0 0 0		V <sub>CC</sub> 5.5 5.5
T <sub>A</sub>	Operating Free-Air Temperature	-55	+125	°C	
t <sub>r</sub> , t <sub>f</sub>	Input Transition Rise or Fall Rate			ns/V	
	Functions 14 and 17	0	No Limit		
	All Other Functions	V <sub>CC</sub> = 1.65 V to 1.95 V	0		20
		V <sub>CC</sub> = 2.3 V to 2.7 V	0		20
		V <sub>CC</sub> = 3.0 V to 3.6 V	0		10
V <sub>CC</sub> = 4.5 V to 5.5 V		0	5		

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

# NLV18SZxx, NLV28WZxx

**Table 3. DC ELECTRICAL CHARACTERISTICS**

Symbol	Parameter	Condition	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			-55°C ≤ T <sub>A</sub> ≤ 125°C		Units
				Min	Typ	Max	Min	Max	
V <sub>T+</sub>	Positive Input Threshold Voltage		1.65	-	1.0	1.4	-	1.4	V
			2.3	-	1.5	1.8	-	1.8	
			2.7	-	1.7	2.0	-	2.0	
			3.0	-	1.9	2.2	-	2.2	
			4.5	-	2.7	3.1	-	3.1	
			5.5	-	3.3	3.6	-	3.6	
V <sub>T-</sub>	Negative Input Threshold Voltage		1.65	0.2	0.5	-	0.2	-	V
			2.3	0.4	0.75	-	0.4	-	
			2.7	0.5	0.87	-	0.5	-	
			3.0	0.6	1.0	-	0.6	-	
			4.5	1.0	1.5	-	1.0	-	
			5.5	1.2	1.9	-	1.2	-	
V <sub>H</sub>	Input Hysteresis Voltage		1.65	0.1	0.48	0.9	0.1	0.9	V
			2.3	0.25	0.75	1.1	0.25	1.1	
			2.7	0.3	0.83	1.15	0.3	1.15	
			3.0	0.4	0.93	1.2	0.4	1.2	
			4.5	0.6	1.2	1.5	0.6	1.5	
			5.5	0.7	1.4	1.7	0.7	1.7	

**NLV18SZU04 (Under Development)**

V <sub>IH</sub>	High-Level Input Voltage		1.65 to 1.95	0.85 V <sub>CC</sub>	-	-	0.85 V <sub>CC</sub>	-	V
			2.3 to 5.5	0.80 V <sub>CC</sub>	-	-	0.80 V <sub>CC</sub>	-	
V <sub>IL</sub>	Low-Level Input Voltage		1.65 to 1.95	-	-	0.15 V <sub>CC</sub>	-	0.15 V <sub>CC</sub>	V
			2.3 to 5.5	-	-	0.20 V <sub>CC</sub>	-	0.20 V <sub>CC</sub>	

**ALL OTHER PARTS**

V <sub>IH</sub>	High-Level Input Voltage		1.65 to 1.95	0.65 V <sub>CC</sub>	-	-	0.65 V <sub>CC</sub>	-	V
			2.3 to 5.5	0.70 V <sub>CC</sub>	-	-	0.70 V <sub>CC</sub>	-	
V <sub>IL</sub>	Low-Level Input Voltage		1.65 to 1.95	-	-	0.35 V <sub>CC</sub>	-	0.35 V <sub>CC</sub>	V
			2.3 to 5.5	-	-	0.30 V <sub>CC</sub>	-	0.30 V <sub>CC</sub>	

**ALL PARTS**

V <sub>OH</sub>	High-Level Output Voltage	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	1.65 to 5.5	V <sub>CC</sub> - 0.1	V <sub>CC</sub>	-	V <sub>CC</sub> - 0.1	-	V
		I <sub>OH</sub> = -100 μA	1.65	1.29	1.4	-	1.29	-	
		I <sub>OH</sub> = -4 mA	2.3	1.9	2.1	-	1.9	-	
		I <sub>OH</sub> = -8 mA	2.7	2.2	2.4	-	2.2	-	
		I <sub>OH</sub> = -12 mA	3.0	2.4	2.7	-	2.4	-	
		I <sub>OH</sub> = -16 mA	3.0	2.3	2.5	-	2.3	-	
		I <sub>OH</sub> = -24 mA	4.5	3.8	4.0	-	3.8	-	
V <sub>OL</sub>	Low-Level Output Voltage	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	1.65 to 5.5	-	-	0.1	-	0.1	V
		I <sub>OL</sub> = 100 μA	1.65	-	0.08	0.24	-	0.24	
		I <sub>OL</sub> = 4 mA	2.3	-	0.2	0.3	-	0.3	
		I <sub>OL</sub> = 8 mA	2.7	-	0.22	0.4	-	0.4	
		I <sub>OL</sub> = 12 mA	3.0	-	0.28	0.4	-	0.4	
		I <sub>OL</sub> = 16 mA	3.0	-	0.38	0.55	-	0.55	
		I <sub>OL</sub> = 24 mA	4.5	-	0.42	0.55	-	0.55	
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	1.65 to 5.5	-	-	±0.1	-	±1.0	μA
I <sub>OZ</sub>	3-State Output Leakage Current	V <sub>OUT</sub> = 0 V to 5.5 V	1.65 to 5.5	-	-	±0.5	-	±5.0	μA

# NLV18SZxx, NLV28WZxx

**Table 3. DC ELECTRICAL CHARACTERISTICS**

Symbol	Parameter	Condition	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			-55°C ≤ T <sub>A</sub> ≤ 125°C		Units
				Min	Typ	Max	Min	Max	
<b>ALL PARTS</b>									
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0	-	-	1.0	-	10	μA
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	-	-	1.0	-	10	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. The V<sub>OH</sub> parameter does not apply to devices with open-drain output, NLV18SZ06, NLV18SZ07, NLV18SZT05 and NLV18SZT07.

**Table 4. AC ELECTRICAL CHARACTERISTICS** (t<sub>R</sub> = t<sub>F</sub> = 3.0 ns)

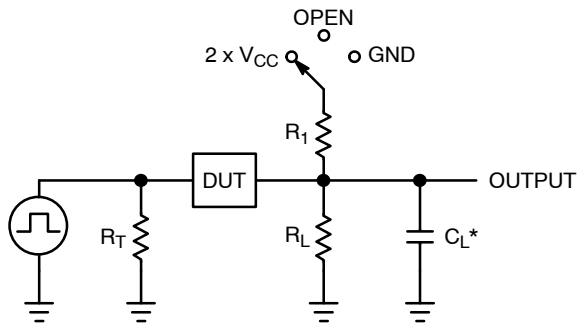
Symbol	Parameter	Condition	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			-55°C ≤ T <sub>A</sub> ≤ 125°C		Units
				Min	Typ	Max	Min	Max	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay, (A or B) to Y (Figures 1 and 2)	R <sub>L</sub> = 1 MΩ, C <sub>L</sub> = 15 pF	1.65 to 1.95	-	9.1	15	-	15.6	ns
		R <sub>L</sub> = 1 MΩ, C <sub>L</sub> = 15 pF	2.3 to 2.7	-	5.0	9.0	-	9.5	
		R <sub>L</sub> = 1 MΩ, C <sub>L</sub> = 15 pF	3.0 to 3.6	-	3.7	6.3	-	6.5	
		R <sub>L</sub> = 500 Ω, C <sub>L</sub> = 50 pF		-	4.4	7.2	-	7.5	
		R <sub>L</sub> = 1 MΩ, C <sub>L</sub> = 15 pF	4.5 to 5.5	-	3.1	5.2	-	5.5	
		R <sub>L</sub> = 500 Ω, C <sub>L</sub> = 50 pF		-	3.7	5.9	-	6.2	
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time, (A or OE or OE) to Y (Figures 1 and 2)		1.65 to 1.95	-	6.5	9.5	-	10	ns
			2.3 to 2.7	-	3.6	8.5	-	9.0	
			3.0 to 3.6	-	2.8	6.2	-	6.5	
			4.5 to 5.5	-	2.0	5.5	-	5.8	
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output Disable Time, (A or OE or OE) to Y (Figures 1 and 2)		1.65 to 1.95	-	5.0	10	-	10.5	ns
			2.3 to 2.7	-	3.3	8.0	-	8.5	
			3.0 to 3.6	-	2.7	5.7	-	6.0	
			4.5 to 5.5	-	2.6	4.7	-	5.0	

**Table 5. CAPACITIVE CHARACTERISTICS** (t<sub>R</sub> = t<sub>F</sub> = 3.0 ns)

Symbol	Parameter	Condition	Typical	Units
C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 0 V or V <sub>CC</sub>	2.5	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 0 V or V <sub>CC</sub>	2.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	10 MHz, V <sub>CC</sub> = 3.3 V, V <sub>IN</sub> = 0 V or V <sub>CC</sub>	9	pF
		10 MHz, V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 0 V or V <sub>CC</sub>	11	

6. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no-load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

# NLV18SZxx, NLV28WZxx

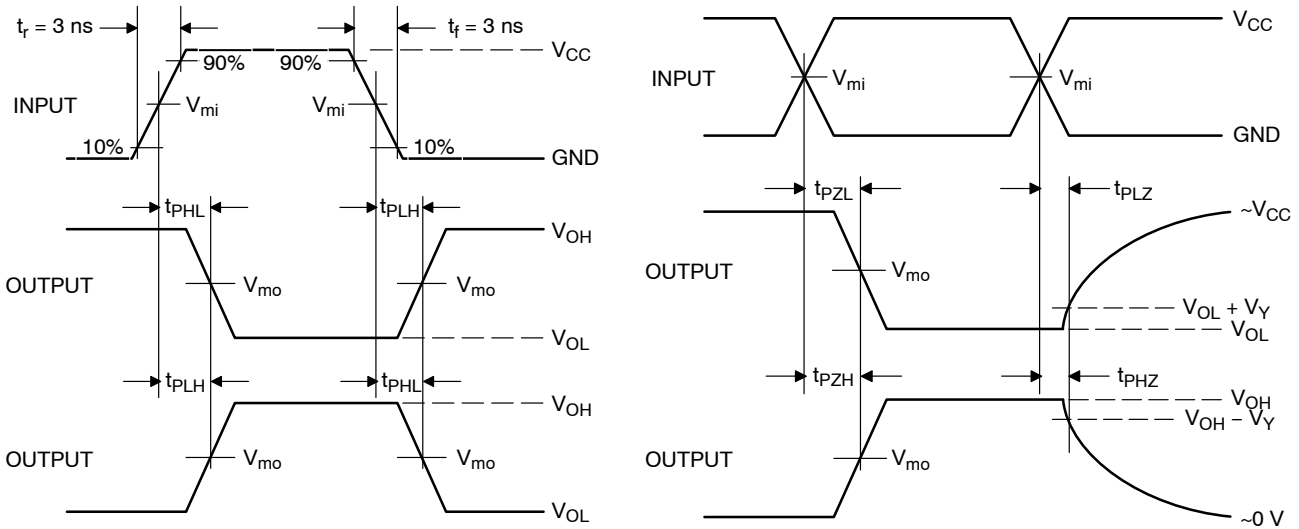


$C_L$  includes probe and jig capacitance  
 $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )  
 $f = 1$  MHz

**Figure 1. Test Circuit**

Test	Switch Position	$C_L$ , pF	$R_L$ , $\Omega$	$R_1$ , $\Omega$
$t_{PLH} / t_{PHL}$	Open	See AC Characteristics Table		
$t_{PLZ} / t_{PZL}$	$2 \times V_{CC}$	50	500	500
$t_{PHZ} / t_{PZH}$	GND	50	500	500

X = Don't Care



**Figure 2. Switching Waveforms**

$V_{CC}$ , V	$V_{mi}$ , V	$V_{mo}$ , V		$V_Y$ , V
		$t_{PLH}$ , $t_{PHL}$	$t_{PZL}$ , $t_{PLZ}$ , $t_{PZH}$ , $t_{PHZ}$	
1.65 to 1.95	$V_{CC}/2$	$(V_{OH} - V_{OL})/2$	$V_{CC}/2$	0.15
2.3 to 2.7	$V_{CC}/2$	$(V_{OH} - V_{OL})/2$	$V_{CC}/2$	0.15
3.0 to 3.6	$V_{CC}/2$	$(V_{OH} - V_{OL})/2$	$V_{CC}/2$	0.3
4.5 to 5.5	$V_{CC}/2$	$(V_{OH} - V_{OL})/2$	$V_{CC}/2$	0.3



# NLV18SZxx, NLV28WZxx

## ORDERING INFORMATION

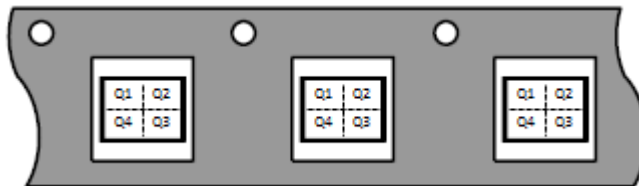
Device	Package	Marking	Pin 1 Orientation (See below)	Shipping†
NLV18SZ00DFT2G	SC-88A	L1	Q4	3000 / Tape & Reel
NLV18SZ02DFT2G	SC-88A	L3	Q4	3000 / Tape & Reel
NLV18SZ04DFT2G	SC-88A	L5	Q4	3000 / Tape & Reel
NLV18SZ06DFT2G (in development)	SC-88A	LF	Q4	3000 / Tape & Reel
NLV18SZ07DFT2G	SC-88A	L7	Q4	3000 / Tape & Reel
NLV18SZ08DFT2G	SC-88A	L2	Q4	3000 / Tape & Reel
NLV18SZ14DFT2G	SC-88A	LA	Q4	3000 / Tape & Reel
NLV18SZ17DFT2G	SC-88A	LX	Q4	3000 / Tape & Reel
NLV18SZ32DFT2G	SC-88A	L4	Q4	3000 / Tape & Reel
NLV18SZ16DFT2G (in development)	SC-88A	LR	Q4	3000 / Tape & Reel
NLV18SZ86DFT2G (in development)	SC-88A	L8	Q4	3000 / Tape & Reel
NLV18SZ125DFT2G	SC-88A	M0	Q4	3000 / Tape & Reel
NLV18SZ126DFT2G (in development)	SC-88A	M2	Q4	3000 / Tape & Reel
NLV18SZU04DFT2G (in development)	SC-88A	L6	Q4	3000 / Tape & Reel
NLV28WZ16DFT2G	SC-88	MR	Q4	3000 / Tape & Reel
NLV28WZU04DFT2G	SC-88	M6	Q4	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

### Pin 1 Orientation in Tape and Reel

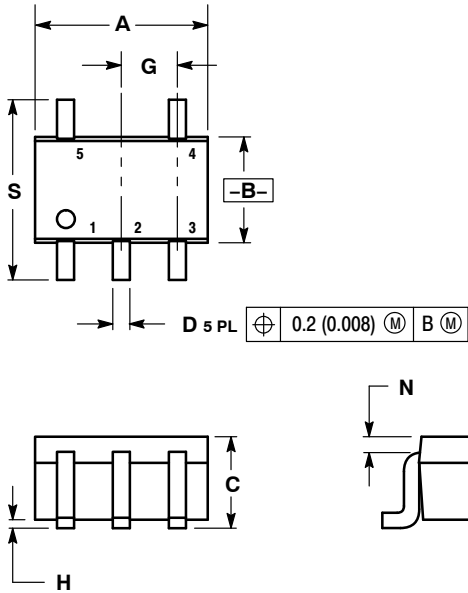
Direction of Feed



# NLV18SZxx, NLV28WZxx

## PACKAGE DIMENSIONS

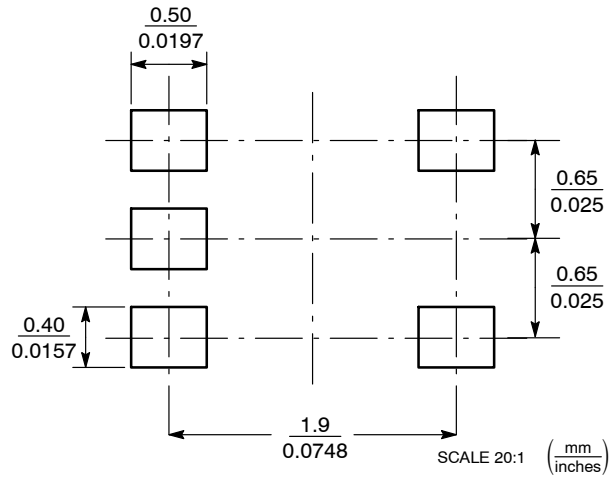
SC-88A (SC-70-5/SOT-353)  
CASE 419A-02  
ISSUE L



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
  4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
H	---	0.004	---	0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20

## SOLDER FOOTPRINT

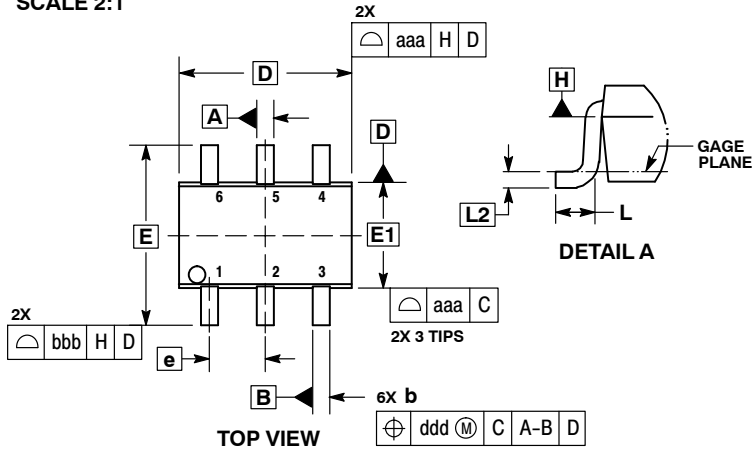
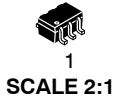


# NLV18SZxx, NLV28WZxx

## PACKAGE DIMENSIONS

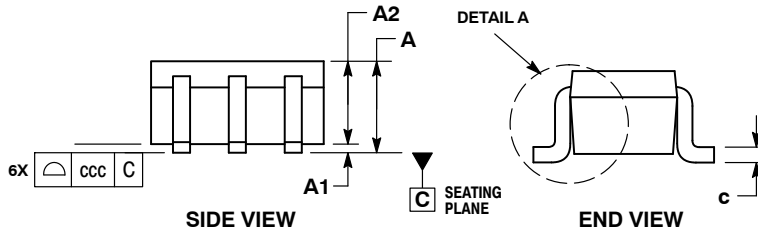
SC-88/SC70-6/SOT-363  
CASE 419B-02  
ISSUE Y

DATE 11 DEC 2012

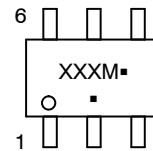


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GAGE BURRS SHALL NOT EXCEED 0.20 PER END.
  4. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H.
  5. DATUMS A AND B ARE DETERMINED AT DATUM H.
  6. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.
  7. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION b AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	---	---	1.10	---	---	0.043
A1	0.00	---	0.10	0.000	---	0.004
A2	0.70	0.90	1.00	0.027	0.035	0.039
b	0.15	0.20	0.25	0.006	0.008	0.010
C	0.08	0.15	0.22	0.003	0.006	0.009
D	1.80	2.00	2.20	0.070	0.078	0.086
E	2.00	2.10	2.20	0.078	0.082	0.086
E1	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65 BSC			0.026 BSC		
L	0.26	0.36	0.46	0.010	0.014	0.018
L2	0.15 BSC			0.006 BSC		
aaa	0.15			0.006		
bbb	0.30			0.012		
ccc	0.10			0.004		
ddd	0.10			0.004		



### GENERIC MARKING DIAGRAM\*



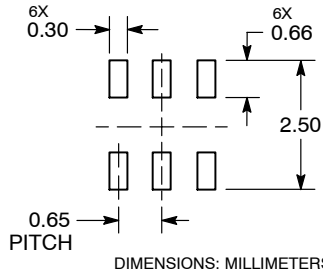
- XXX = Specific Device Code
- M = Date Code\*
- = Pb-Free Package

(Note: Microdot may be in either location)


\*Date Code orientation and/or position may vary depending upon manufacturing location.

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

### RECOMMENDED SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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